

January 2008

74LVTH273 Low Voltage Octal D-Type Flip-Flop with Clear

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bushold on the data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Outputs source/sink -32mA/+64mA
- Functionally compatible with the 74 series 273
- Latch-up performance exceeds 500mA
- ESD performance:
 - Human-body model > 2000V
 - Machine model > 200V
 - Charged-device model > 1000V

General Description

The LVTH273 is a high-speed, low-power positive-edge-triggered octal D-type flip-flop featuring separate D-type inputs for each flip-flop. A buffered Clock (CP) and Clear (CLR) are common to all flip-flops.

The state of each D-type input, one setup time before the positive clock transition, is transferred to the corresponding flip-flop's output.

The LVTH273 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal flip-flops are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH273 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Ordering Information

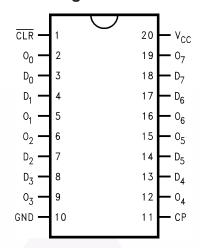
Order Number	Package Number	Package Description			
74LVTH273WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide			
74LVTH273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
74LVTH273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.



All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram



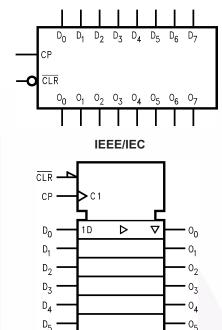
Pin Description

Pin Names	Description
D ₀ –D ₇	Data Inputs
СР	Clock Pulse Input
CLR	Clear
O ₀ -O ₇	Outputs

Functional Description

The LVTH273 consists of eight positive-edge-triggered flip-flops with individual D-type inputs. The buffered Clock and Clear are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. When the Clock is either HIGH or LOW, the D-input signal has no effect at the output. When the Clear ($\overline{\text{CLR}}$) is LOW, all Outputs will be forced LOW.

Logic Symbols



Truth Table

 D_6

	Inputs				
D _n	CP	CLR	O _n		
Н	_	Н	Н		
L	_	Н	L		
Х	H or L	Н	O _o		
Х	Х	L	L		

H = HIGH Voltage Level

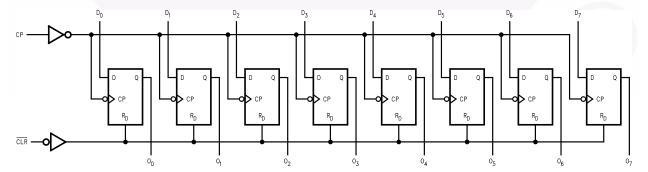
L = LOW Voltage Level

X = Immaterial

∠ = LOW-to-HIGH Transition

O_o = Previous O_o before HIGH-to-LOW of CP

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +4.6V
V _I	DC Input Voltage	-0.5V to +7.0V
Vo	DC Output Voltage [,] Output in HIGH or LOW State ⁽¹⁾	-0.5V to +7.0V
I _{IK}	DC Input Diode Current, V _I < GND	-50mA
I _{OK}	DC Output Diode Current, V _O < GND	-50mA
Io	DC Output Current, V _O > V _{CC}	
	Output at HIGH State	64mA
	Output at LOW State	128mA
I _{CC}	DC Supply Current per Supply Pin	±64mA
I _{GND}	DC Ground Current per Ground Pin	±128mA
T _{STG}	Storage Temperature	–65°C to +150°C

Note:

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min	Max	Units
V _{CC}	Supply Voltage	2.7	3.6	V
V _I	Input Voltage	0	5.5	V
I _{OH}	HIGH-Level Output Current		-32	mA
I _{OL}	LOW-Level Output Current		64	mA
T _A	Free-Air Operating Temperature	-40	85	°C
Δt / ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

^{1.} I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

			V _{CC}		T _A =-4	0°C to +	85°C	
Symbol	Param	eter	(V)	Conditions	Min.	Typ. ⁽²⁾	Max.	Units
V _{IK}	Input Clamp Dio	de Voltage	2.7	I _I = -18mA			-1.2	V
V _{IH}	Input HIGH Volta	ige	2.7–3.6	$V_O \le 0.1V$ or	2.0			V
V _{IL}	Input LOW Voltag	ge	2.7-3.6	$V_O \ge V_{CC} - 0.1V$			0.8	V
V _{OH}	Output HIGH Vol	tage	2.7-3.6	$I_{OH} = -100\mu A$	V _{CC} - 0.2			V
			2.7	$I_{OH} = -8mA$	2.4			
			3.0	$I_{OH} = -32mA$	2.0			
V _{OL}	Output LOW Volt	age	2.7	$I_{OL} = 100 \mu A$			0.2	V
				I _{OL} = 24mA			0.5	
			3.0	I _{OL} = 16mA			0.4	
				$I_{OL} = 32mA$			0.5	
				$I_{OL} = 64 \text{mA}$			0.55	
I _{I(HOLD)}	Bushold Input Mi	inimum Drive	3.0	$V_{I} = 0.8V$	75			μΑ
				V _I = 2.0V	- 75			
I _{I(OD)}	Bushold Input Ov		3.0	(3)	500			μΑ
	Current to Chang	ge State		(4)	-500			
I _I	Input Current		3.6	$V_1 = 5.5V$			10	μΑ
		Control Pins	3.6	$V_I = 0V \text{ or } V_{CC}$			±1	
		Data Pins	3.6	$V_I = 0V$			- 5	
				$V_I = V_{CC}$			1	
I _{OFF}	Power Off Leakage Current		0	$0V \le V_I \text{ or } V_O \le 5.5V$			±100	μΑ
I _{CCH}	Power Supply Current		3.6	Outputs HIGH			0.19	mA
I _{CCL}	Power Supply Current		3.6	Outputs LOW			5	mA
Δl _{CC}	Increase in Powe	er Supply	3.6	One Input at V _{CC} – 0.6V,			0.2	mA
	Current ⁽⁵⁾			Other Inputs at V _{CC} or GND				

Notes:

- 2. All typical values are at $V_{CC} = 3.3V$, $T_A = 25$ °C.
- 3. An external driver must source at least the specified current to switch from LOW-to-HIGH.
- 4. An external driver must sink at least the specified current to switch from HIGH-to-LOW.
- 5. This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics⁽⁶⁾

			Conditions	T _A = 25°C			
Symbol	Parameter	V _{CC} (V)	$C_L = 50 pF, R_L = 500 \Omega$	Min.	Тур.	Ma.x	Units
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	(7)		0.8		V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	(7)		-0.8		V

Notes:

- 6. Characterized in SOIC package. Guaranteed parameter, but not tested.
- 7. Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

					40°C to - 0pF, R _L =			
			Vo	$_{C} = 3.3V \pm$	0.3V	V _{CC} =	= 2.7V	
Symbol		Parameter	Min.	Typ. ⁽⁸⁾	Max.	Min.	Max.	Units
f _{MAX}	Maximum Clock Frequency					150		MHz
t _{PLH}	Propagation Delay. CP to O _n		1.7		4.9	1.7	5.5	ns
t _{PHL}			1.9		4.8	1.9	5.1	
t _{PHL}	Propagation Delay CLR to On		1.6		4.8	1.6	5.4	ns
t _W	Pulse Duration		3.3			3.3		ns
t _S	Setup Time	Data HIGH or LOW before C	P 2.3			2.7		ns
		CLR HIGH before CP	2.3			2.7		
t _H	Hold Time	Data HIGH or LOW after CP	0			0		ns

Note:

8. All typical values are at $V_{CC} = 3.3V$, $T_A = 25$ °C.

Capacitance⁽⁹⁾

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	3	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_{O} = 0V$ or V_{CC}	6	pF

Note:

9. Capacitance is measured at frequency f = 1MHz, per MIL-STD-883B, Method 3012.

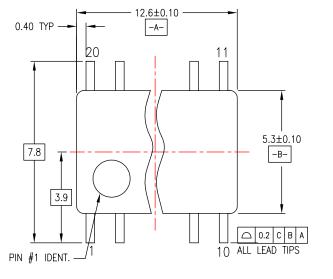
Physical Dimensions 13.00 12.60 11.43 В 9.50 10.65 7.60 10.00 7.40 PIN ONE 0.35 INDICATOR **⊕** 0.25 **M** C B A LAND PATTERN RECOMMENDATION 2.65 MAX SEE DETAIL A 0.33 0.20 0.10 C 0.30 0.10 SEATING PLANE 0.75 0.25 × 45° NOTES: UNLESS OTHERWISE SPECIFIED (R0.10) A) THIS PACKAGE CONFORMS TO JEDEC GAGE PLANE MS-013, VARIATION AC, ISSUE E (R0.10) B) ALL DIMENSIONS ARE IN MILLIMETERS. 0.25 C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS. D) CONFORMS TO ASME Y14.5M-1994 0.40 SEATING PLANE E) LANDPATTERN STANDARD: SOIC127P1030X265-20L (1.40)DETAIL A F) DRAWING FILENAME: MKT-M20BREV3

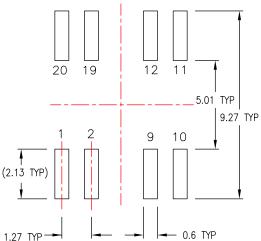
Figure 1. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide

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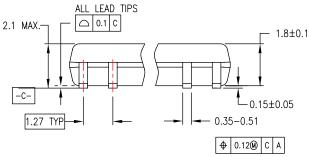
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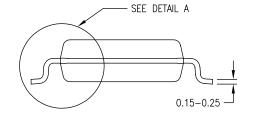
Physical Dimensions (Continued)









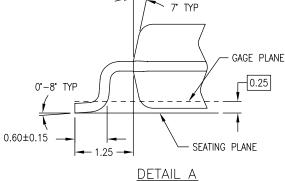


DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

B. DIMENSIONS ARE IN MILLIMETERS.
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M20DREVC

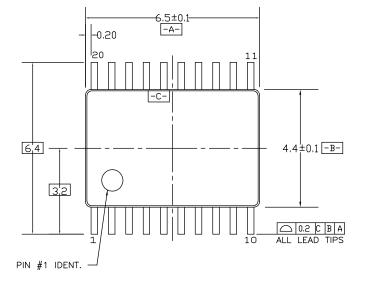
Figure 2. 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

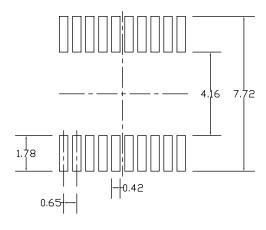
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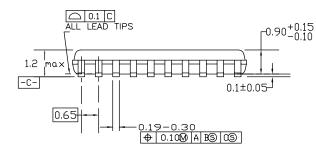
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Physical Dimensions (Continued)





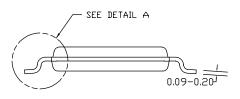
LAND PATTERN RECOMMENDATION

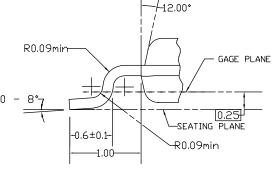




NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MD-153, VARIATION AC, REF NOTE 6, DATE 7/93.
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- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.





DETAIL A

MTC20REVD1

Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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